TOSHIBA

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

TA8466AF

3 PHASE FULL WAVE BRUSHLESS DC MOTOR DRIVER IC

TA8466AF is a semi-linear type 3 Phase Full Wave Brushless DC Motor Driver IC, developed as a cylinder motor driver for stationary VTRs.

FEATURES

Low Noise Soft Switching Drive

One direction Drive

Small Outer Capacitance

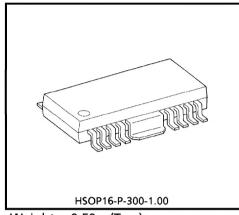
Operating Supply Voltage : $V_{CC} = 7 \sim 17V$

Hall Input Sensitivity : $V_{H} = 30 \text{mV}_{p-p}$

Built-in Protective Diodes for All Input Pins

Built-in Control Amp Reference Voltage (with Output Pins)

Built-in Thermal Shutdown Circuit



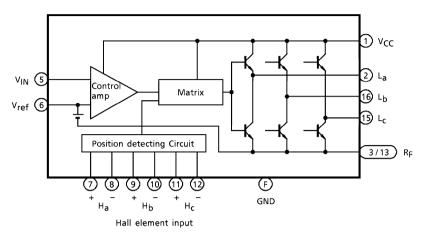
Weight: 0.50g (Typ.)

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BLOCK DIAGRAM

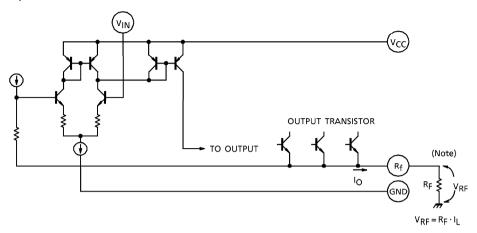


Pins 4 and 4 are NC. Keep Pin 6 open.

PIN FUNCTION

PIN No.	SYMBOL	FUNCTIONAL
1	V _{CC}	Supply voltage input pin
2	La	a-phase drive output pin
3	R_F	Output current detecting pin
4	N.C.	N.C. pin
5	VIN	Control amp positive input pin
6	V _{ref}	Control amp reference voltage output pin
7	H _a +	a-phase Hall amp positive input pin
8	H _a -	a-phase Hall amp negative input pin
9	H _b +	b-phase Hall amp positive input pin
10	H _b -	b-phase Hall amp negative input pin
11	H _c +	c-phase Hall amp positive input pin
12	H _c -	c-phase Hall amp negative input pin
13	R _F	Output current detecting pin
14	N.C.	N.C. pin
15	L _C	c-phase drive output pin
16	Lb	b-phase drive output pin
F	FIN	(Connect to GND)

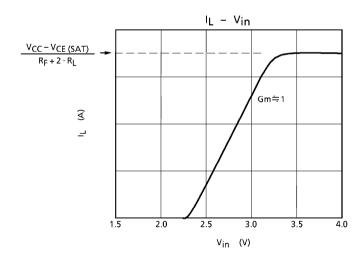
1. Control input circuit



Feedback circuit of output currents is built into IC, that is, the voltage feedback is proportional to the output current in RF.

(Note) The common impedance inside IC is taken into consideration in providing two RF terminals. Short two pins (3 and 3) in using them.

INPUT / OUTPUT CHARACTERISTICS



: Output coil resistance $V_{\mbox{CE (SAT)}}$: Output transistor saturation voltage

(upper/lower total)

MAXIMUM RATINGS (Ta = 25°C)

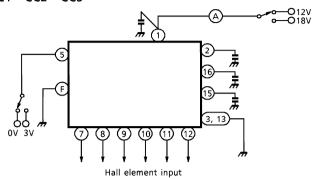
CHARACTERISTIC	SYMBOL	RATING	UNIT		
Supply Voltage	V _{CC}	18	V		
Output Current	lO (MAX.)	0.7	Α		
Bower Dissipation	D	(Note 1) 0.9	W		
Power Dissipation	PD	(Note 2) 8.3] '' 		
Operating Temperature	T _{opr}	- 30~75	°C		
Storage Temperature	T _{stg}	- 55∼150	°C		

(Note 1) Single body (Note 2) Infinite heat sink mounting

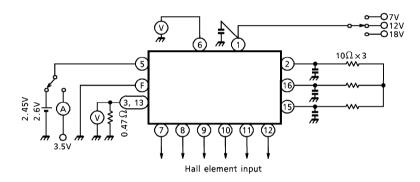
ELECTRICAL CHARACTERISTICS ($V_{CC} = 12V$, Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CIR- CUIT	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Supply Current			I _{CC1}	1	Output open, $V_{IN} = 0V$	1.5	3.0	4.5	mA
			I _{CC2}		Output open, $V_{IN} = 3V$	18	50	95	
			lCC3	'	Output open, $V_{CC} = 18V$, $V_{IN} = 3V$	18	55	110	
	Reference Voltage		V _{ref}	2		2.25	2.35	2.45	٧
Control Amp	Control Gain		Gm		$R_F = 0.47\Omega$, $V_{IN} = 2.45V/2.6V$	_	1.0	_	A/V
	Input Current		lin		V _{IN} = 3.5V	_	2.5	10	μΑ
	Reference Voltage Ripple Compression Rate		R _r		V _{CC} = 7V / 18V	- 53	- 64		dB
Leak Current Side		Upper Side	lOL (U)	- 3	V _{CC} = 18V		-	50	μΑ
		Lower Side	lOL (L)		V _{CC} = 18V	1	l	50	
Catamatia		Upper Side	V _{sat} (U)	4	I _L = 0.7A		1.2	1.6	v
Saturation Voltage		Lower Side	V _{sat (L)}	4	I _L = 0.7A		0.5	0.85	
Residual Output Voltage		VOR	2	V _{IN} = 0V		0	12	mV	
Hall Amp	Difference Input Voltage Range		VH	6		30	_	200	mV _{p-p}
	Common-Mode Input Voltage Range		VCMRH	5		2.0	_	V _{CC} – 3	V
Thermal Shutdown Operating Temperature		TSD	_		_	175	_	°C	

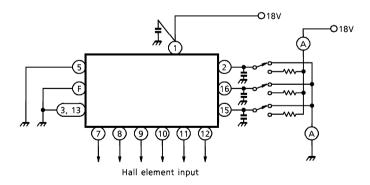
TEST CIRCUIT 1 I_{CC1}, I_{CC2}, I_{CC3}



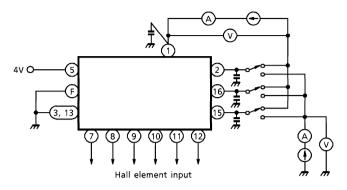
TEST CIRCUIT 2 V_{ref} , G_V , I_{in} , R_r , Vor



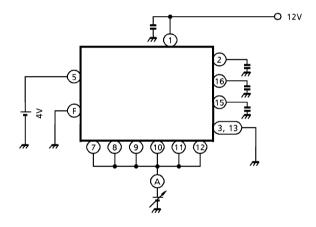
TEST CIRCUIT 3 IOL (U), IOL (L)



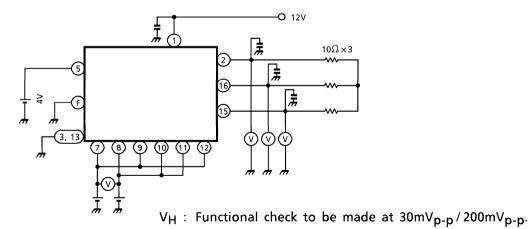
TEST CIRCUIT 4 V_{sat (U)}, V_{sat (L)}



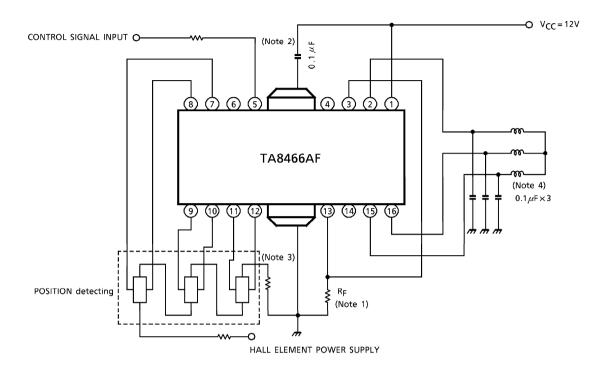
TEST CIRCUIT 5 VCMRH



TEST CIRCUIT 6 V_H



APPLICATION CIRCUIT

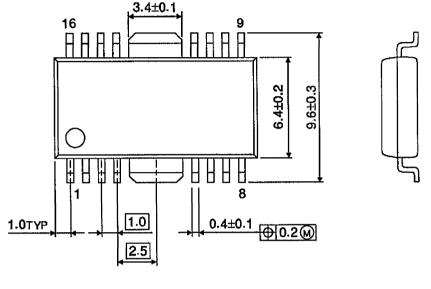


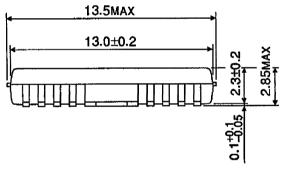
- (Note 1) R_F value is determined by coil impedance, F/V conversion voltage (control input), and necessary activation torque. But determine it at about $0.3 \sim 5\Omega$.
- (Note 2) Connect this condenser directly to IC fin (GND). Still larger capacity may be necessary depending upon common impedance among supply lines.
- (Note 3) Write Hall sensor GND line and coil current RF line without common impedance.
- (Note 4) It may be necessary to change condenser capacity depending upon motor type, to prevent noise and oscillation.
- (Note 5) Utmost care is necessary in the design of the output line, V_{CC} and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.

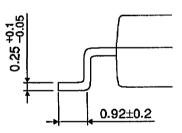
OUTLINE DRAWING

HSOP16-P-300-1.00









Weight: 0.50g (Typ.)